DSA5002

Silicon PNP epitaxial planar type

For general amplification Complementary to DSC5002

Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- Eco-friendly Halogen-free package

Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-60	V
Collector-emitter voltage (Base open)	V _{CEO}	-50	V
Emitter-base voltage (Collector open)	V _{EBO}	-5	V
Collector current	I _C	-500	mA
Peak collector current	I _{CP}	-1	А
Collector power dissipation	P _C	150	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Package

- Code
- SMini3-F2-B
- Pin Name
 - 1. Base
 - 2. Emitter
 - 3. Collector

Marking Symbol: A2

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = -10 \ \mu \text{A}, I_{\rm E} = 0$	-60			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = -10 \ \mu A, I_{\rm C} = 0$	-5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = -20 \text{ V}, I_E = 0$			- 0.1	μΑ
Forward current transfer ratio *1	h _{FE1} *2	$V_{\rm CE} = -10$ V, $I_{\rm C} = -150$ mA	120		340	
	h _{FE2}	$V_{\rm CE} = -10$ V, $I_{\rm C} = -500$ mA	40			
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = -300 \text{ mA}, I_{\rm B} = -30 \text{ mA}$		- 0.2	- 0.6	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_{\rm C} = -300 \text{ mA}, I_{\rm B} = -30 \text{ mA}$		- 0.9	-1.5	V
Transition frequency	\mathbf{f}_{T}	$V_{\rm CE} = -10$ V, $I_{\rm C} = -50$ mA		130		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		7.3	15	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

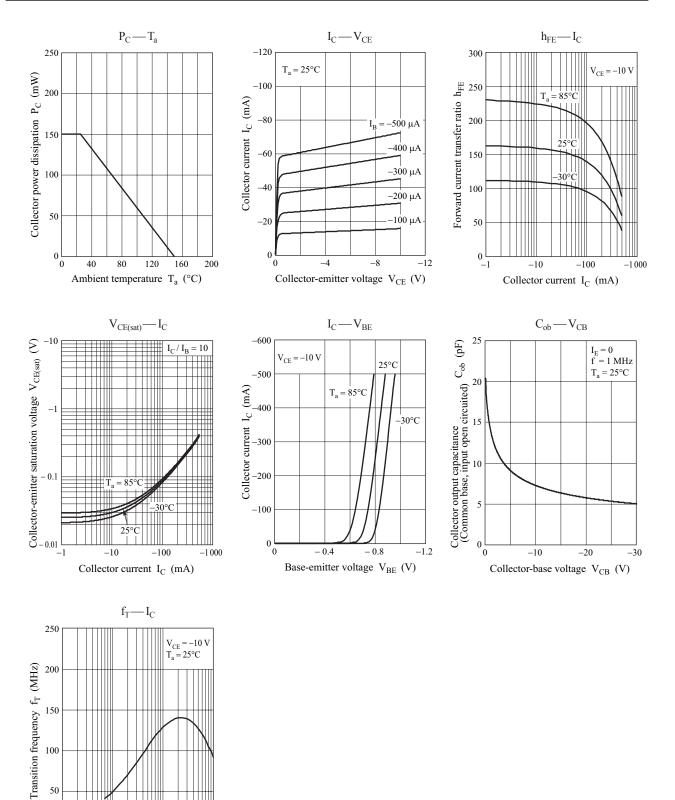
*2: Rank classification

Code	R	S	0
Rank	R	S	No-rank
$h_{\rm FE1}$	120 to 240	170 to 340	120 to 340
Marking Symbol	A2R	A2S	A2

Product of no-rank is not classified and have no marking symbol for rank.

DSA5002

Panasonic



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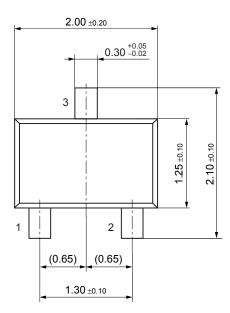
Collector current I_C (mA)

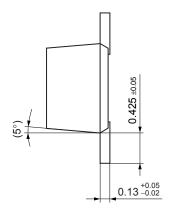
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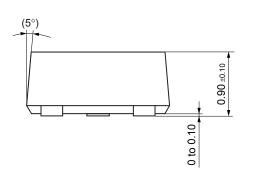
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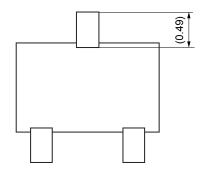
SMini3-F2-B

Unit: mm









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